

RAMAN GAIN AND STRUCTURAL OF TELLURITE-PHOSPHATE GLASSES WITH DIFFERENT MODIFIERS DOPING WITH Er₂O₃

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A glass series of Te-glasses (70TeO₂- 10P₂O₅- 10ZnO- 5PbF₂) modified with 5mol % of different modifiers (WO₃, Al₂O₃, CdO, SrO, BaO), that was then doped with 600ppm Er₂O₃ was prepared by melt quench technique. The effect of modifier oxide on the Te-glass structure was studied using Raman spectroscopy. The Obtained Raman spectra reveal the characteristic structural units TeO₄ and TeO₃. Er₂O₃ doping along with the type of oxide modifier influenced the tellurite glass network and hence the Raman spectral features. The change in the Boson peak features depend on the rare earth ion doping. The obtained Raman spectra were deconvoluted to follow the structural changes. The deconvoluted data show a transformation of TeO₄ to TeO₃ upon the addition of metal oxides. Due to the higher coordination of WO₃ and Al₂O₃ that offers more oxygens when compared with alkaline modifiers, the TeO₃ structural group is dominated. Raman gain was calculated for the prepared glasses. Al₂O₃ modified glass sample has the highest Raman gain.

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1. Introduction

Compared to phosphate and Silicate glasses, tellurium dioxide based glasses have great interest due to their physical and chemical properties such as low phonon energy (640–790cm⁻¹) vibration bands for the trigonal pyramid, bipyramid and polyhedral that makes them attractive for designing of Raman amplifiers, sensors, switching devices, near-IR and mid-IR lasers [1- 3], Beside their low melting temperature, good solubility of rare-earth ions and large thermo-optic coefficient, tellurium glasses also characterized by high refractive index, high dielectric constant, wide infrared transparency and excellent third-order nonlinear optical properties [4- 7]. Adding fluorides such as PbF₂, BaF₂, LiF, ZnF₂...etc, to glass matrix lower the non-radiative decay rates and improve the emission efficiency [8-10]. The glass-forming ability of tellurite glasses enhances by adding modifiers such as transition metal, alkali, alkaline-earth and rare earth metal oxides [11] and modify the main structural units TeO₄ and TeO₃ of Tellurite glasses. The addition of alkaline earth oxides such as BaO and SrO increases the thermal stability of the glasses [12, 13]. Also, heavy metal oxides (ZnO, PbO and CdO) based glasses have a wide range of applications in the field of optical and electronic devices [14, 15]. Chemical and thermal stability of tellurite glass increase with the addition of Al₂O₃ that lead also to the transformation: TeO₄ → TeO₃ [16, 13]. Also adding Al₂O₃ to the RE doped glass matrix enhance the dispersion of rare earth in glasses, helping to limit the concentration quenching of the photoluminescence features [17]. Addition of WO₃ into TeO₂ results in the formation of W–O–W and Te–O–W linkages. The formation of Te–O–W bridging bonds increases the connectivity of the network and stabilizes the glass formation.

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It also leads to increasing lower co-ordination units $\text{TeO}_3/\text{TeO}_{3+1}$ at the expense of higher coordination TeO_4 units in the glass network [18]. The addition of WO_3 leads to good electrochromic and photochromic properties so it could be widely used in electrochromic, optical modulation and solar energy [19]. Besides their high rare-earth solubility, tellurite glasses also prevent erbium clustering and luminescence quenching, so Er-doped tellurite glasses exhibit a broad emission at $1.53 \mu\text{m}$ with a high quantum efficiency [20-23]. Tellurium glasses doped with Er^{3+} are good candidates for applications such as optical amplifiers, laser light modulators and fibre lasers [24, 25]. Dousti et al. reported that the up-conversion process is enhanced in zinc tellurite glass doped with Er^{3+} ion [26]. Raman gain has received great interest because it is considered as a mean for all-optical amplification processes [27]. TeO_2 glasses are characterized by their high Raman gain when compared with SiO_2 glasses [28]. Erbium-doped P_2O_5 -tellurite glasses are a good candidate for waveguide amplifiers at $\lambda=1.5 \mu\text{m}$ [29].

The aim of this paper is to investigate the effect of different modifier oxides with different coordination on the structure and Raman gain of undoped 70TeO_2 - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 glasses and when doped with Er_2O_3 .

2. Experimental

The glasses with the composition (70TeO_2 - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2) modified with 5mol % of different modifiers (WO_3 , Al_2O_3 , CdO , SrO , BaO) by using melt- quenching method, that was then doped with 600ppm Er_2O_3 . Where the composition 70TeO_2 - 5WO_3 - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 (label W), 70TeO_2 - 5WO_3 - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 + 600ppm Er_2O_3 (Label W-Er), 70TeO_2 - 5CdO - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 (Label Cd), 70TeO_2 - 5CdO - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 +600ppm Er_2O_3 (Label Cd-Er), 70TeO_2 - $5\text{Al}_2\text{O}_3$ - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 (Label Al), 70TeO_2 - $5\text{Al}_2\text{O}_3$ - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 + 600ppm Er_2O_3 (Label Al-Er), 70TeO_2 - 5SrO - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 (Label Sr), 70TeO_2 - 5SrO - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 + 600ppm Er_2O_3 (Label Sr-Er), 70TeO_2 - 5BaO - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 (Label Ba), and 70TeO_2 - 5BaO - $10\text{P}_2\text{O}_5$ - 10ZnO - 5PbF_2 (Label Ba-Er). The Spontaneous Raman spectra of the prepared glass which are vertically (VV) polarized were acquired using Thermo Scientific DXR Raman Microscope Spectroscopy setup with 532nm excitation [532nm Laser type Diode-pumped, solid state (DPSS)]. The V-polarized Raman scattered signal was collected in the backscattering geometry with a $100\times$ microscope objective.

3. Results and discussion

Raman spectra of the prepared undoped and Er_2O_3 doped TeO_2 glasses are characterized by two broad envelopes cover the range from 250 to 550cm^{-1} and from 620 to 1000cm^{-1} . These two envelopes could be deconvoluted to 4 centers around 450, 650, 720 and 980cm^{-1} . The first center that is found around 450cm^{-1} is assigned to bending and stretching vibrations of Te-O-Te linkages that are affected with the added modifier [30- 32]. The Raman band around 650cm^{-1} could be assigned to asymmetric stretching vibrations of TeO_4 units [30, 33, 34]. The third deconvoluted center that is found around 720-770 is assigned to symmetric and asymmetric stretching modes of TeO_3 [30, 31]. While the Raman center around 980-1100 is assigned to symmetric and asymmetric stretching fundamental of PO_4 tetrahedral groups [35]. The edge at low frequency $< 200\text{cm}^{-1}$ is due to the Boson peak which confirms the glassy structure. It shifts depending on the glass composition because of the change in the density of vibrational states [36, 37]. To reach charge neutrality condition, when TeO_2 glass is doped with rare-earth ions, REs ions are incorporated at non bridging anion bonds and this shifts Boson peak to lower frequency [38]. Incorporation of WO_3 into TeO_2 glass network leads to the formation of W-O-W and Te-O-W linkages, it is known that W and Te ions have approximately the same electronegativity values, but W ions possess a higher electronic polarizability than Te ions and W-O bond is stronger than Te-O bond so formation of Te-O-W bridging bonds increases the connectivity of the glass network [39, 40]. At low concentration of WO_3 , W atoms participate in the glass network as WO_4 that reaches its maximum value at 30 mol% while at higher concentrations W atoms are incorporated

as WO_6 that is characterized by the peak around 350 cm^{-1} [41, 42]. In our prepared WO_3 -modified TeO_2 glass sample the peak around 350 that is assigned to bending vibrations in W-O-W in WO_6 units is absent as this sample contains low concentration of WO_3 that results in the peaks around 450 cm^{-1} that is assigned to Te-O-W stretching vibrations indicating substitution of TeO_4 by WO_4 tetrahedral units. Also, the peak at 920 cm^{-1} is characteristic of asymmetric vibrations of WO_4 tetrahedra [43]. For Al_2O_3 modified TeO_2 glass sample, suggesting a similar transformation of the tetrahedral Te_4 units to Te_3 units also due to the larger number of oxygen atoms introduced when compared to MO modified glasses. The low-frequency peak at $\approx 460\text{ cm}^{-1}$ is enhanced due to the formation of Te-O-Al bridges as their bending contributed to this band [44].

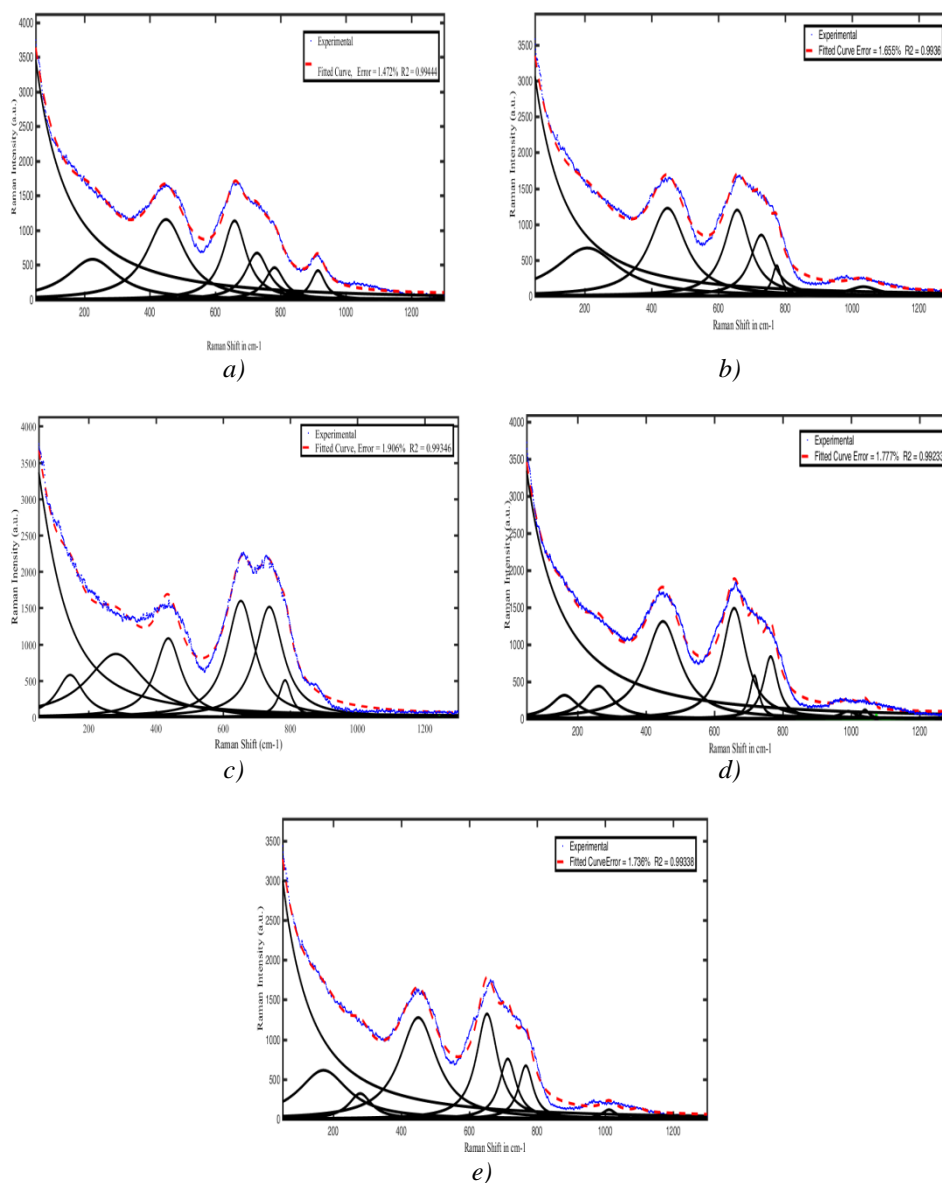


Fig. 1 Raman spectra of prepared glasses: a) WO_3 ; b) CdO ; c) Al_2O_3 ; d) SrO ; e) BaO

Because of similar bond strength of the dissolution of Al-O and Te-O, Al_2O_3 could cross-link strongly the glass network by Te-O-Al bridges. The band observed also around 805 is attributed to the Al-O linkages [44]. The conversion of $\text{TeO}_4 \rightarrow \text{TeO}_3$ by the addition of divalent cation and high basicity oxygen anion is confirmed in many reports of MO- TeO_2 glasses Raman spectra [46-48]. The introduction of ZnO or divalent alkaline-earth ion (M^{2+}) and oxygen anions having high basicity affects the connection of Te-O-Te and leads to the termination of Te-O- with

M^{2+} ions. Finally, TeO_4 units are converted to a TeO_3 with a terminating double bond of $Te=O$ [46]. The deconvoluted data also show that with increasing the electronegativity, the center around 650 cm^{-1} , shifts toward higher energy except Al_2O_3 containing glasses this center is found at lower energy position while the peak center around $720\&770\text{ cm}^{-1}$ shifts toward higher energies $738\&785\text{ cm}^{-1}$ in W&AL containing glasses, see fig.. also have the highest relative intensity, see fig.1. This may be due to the higher coordination of W and Al that offers more oxygen than alkaline modifiers so it has a higher rate of transformation of Te_4 to Te_3 units.

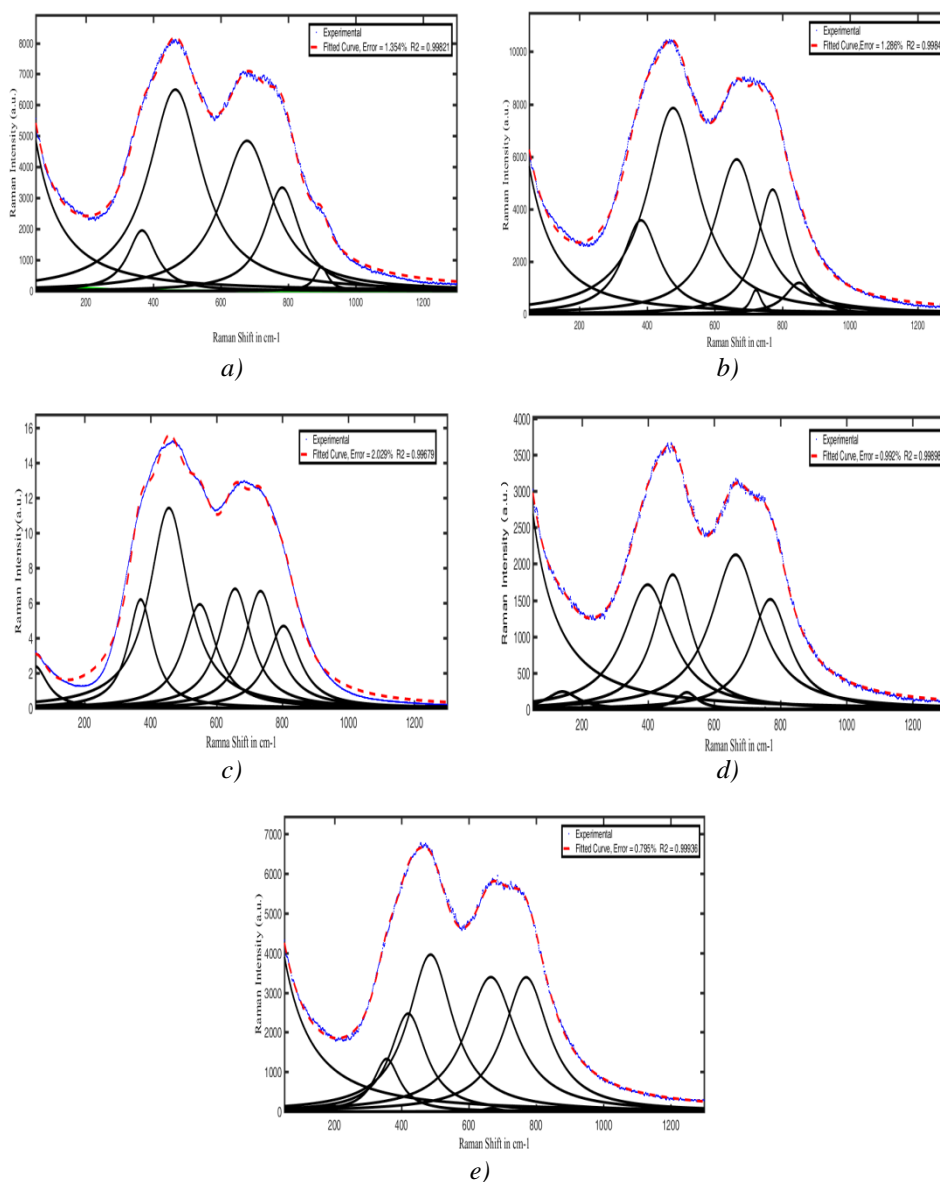


Fig. 2 Deconvolution of Raman spectra of prepared glasses.
a) $WO_3 - Er_2O_3$; b) $Cd - Er_2O_3$; c) $Al - Er_2O_3$; d) $SrO - Er_2O_3$; e) $BaO - Er_2O_3$

Doping with Er_3O_2 oxides causes a shift towards higher energy for Raman bands and especially affects the band assigned to $Te-O$ vibrations in the (TeO_3) ($\approx 750\text{ cm}^{-1}$) [49]. Also, the addition of Er^{3+} shows a band at about 350 cm^{-1} that is attributed to deformed $Te-O-Te$ linkages in the glass network [49, 50]. The area of the band assigned to TeO_4 groups decreases for the benefit of the band assigned to TeO_3 , especially in Al-modified glasses, see Fig. 3. An increase of relative intensity of the band assigned to TeO_3

vibrations after doping is also observed, which confirms the conversion of TeO_4 units into $\text{TeO}_{3+1}/\text{TeO}_3$ units through the formation of NBOs [51].

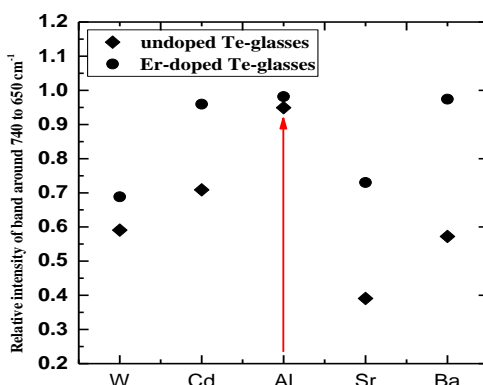


Fig. 3. Relative intensity of band at range 650 to 740nm with different modifier.

The Raman gain coefficient of the prepared glasses can be calculated using the following equations [52- 54]:

$$g_{sam}(\nu) = I_{corr.}(\nu) \times g_{SiO_2} \times \left[\frac{n_{Si}(\nu_1 - \nu_p)}{n_{sam}(\nu_1 - \nu)} \right]^2 \times \left[\frac{(\nu_1 - \nu_p)}{(\nu_1 - \nu)} \right]^3 \quad (1)$$

$$I_{corr.}(\nu) = I_{meas.}(\nu) \cdot F_R(\nu) \cdot F_A(\nu) \cdot \frac{1}{F_{BE}(\nu, T) + 1} \quad (2)$$

$$I_{meas.} \rightarrow \text{measured intensity } F_R(\nu) = \frac{(1+n_{sam})^4 \cdot (n_{Si})^2}{(1+n_{Si})^4 \cdot (n_{sam})^2} \quad (3)$$

$$F_A(\nu) = \frac{(n_{sam})^2}{(n_{Si})^2} \quad (4)$$

$$F_{BE}(\nu, T) = \frac{1}{\exp\left(\frac{hc}{K_B T}\right) - 1} \quad (5)$$

where: h is plank`s constant, C is speed of light, K_B is Boltzman constant, T is the temperature of Raman Experiment, g_{SiO_2} is Raman peak gain of silica which is $1.85 \times 10^{-13} \text{mW}^{-1}$ at $\lambda = 532 \text{nm}$ pumping. ν is Raman shift frequency relative to pump wavelength $\nu_1 = 1.88 \times 10^4 \text{cm}^{-1}$, $\nu_p = 440 \text{cm}^{-1}$. The values of refractive index of for WO_3 and CdO modified glasses are obtained directly from the reference [55] while for Al_2O_3 , SrO and BaO modified glasses, refractive index was calculated from the values of the Energy band gap using the following equation [56]:

$$\left(\frac{n^2 - 1}{n^2 + 2} \right) = 1 - \left(\frac{E_{opt}}{20} \right)^{1/2} \quad (6)$$

E_{opt} was calculated using UV-Vis spectra from previous work ref.[57] using the model proposed by Davis and Mott [58]:

$$\alpha(\nu) = \frac{A(h\nu - E_{opt})^n}{h\nu} \quad (7)$$

where A is an energy-independent constant, E_{opt} is the optical band gap and n is a constant which determines the type of the optical transition. [$n=1/2$: direct allowed transition, $n=2$: Indirect allowed transition, $n=1/3$: direct forbidden transition, $n=3$: indirect forbidden transition], see Table 1.

Table 1. Glasses composition, optical energy gap, and refractive index of prepared glasses.

Sample Code	Composition	E_{opt}	n	Ref
W	70TeO ₂ -5WO ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂	3.03	2.14	55
W-Er	70TeO ₂ -5WO ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	3.01	2.17	55
Cd	70TeO ₂ -5CdO-10P ₂ O ₅ -10ZnO-5PbF ₂	3.41	2.20	55
Cd-Er	70TeO ₂ -5CdO-10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	3.34	2.44	55
Al	70TeO ₂ -5Al ₂ O ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂	2.85	2.44	57
Al-Er	70TeO ₂ -5Al ₂ O ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	2.80	2.45	57
Sr	70TeO ₂ -5SrO-10P ₂ O ₅ -10ZnO-5PbF ₂	2.84	2.44	57
Sr-Er	70TeO ₂ -5SrO-10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	2.885	2.429	57
Ba	70TeO ₂ -5BaO-10P ₂ O ₅ -10ZnO-5PbF ₂	2.833	2.444	57
Ba-Er	70TeO ₂ -5BaO-10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	2.89	2.427	57

The Raman gain peak is found at about 675 cm⁻¹, see Fig.4a,b,c,d. for examples. The obtained value for the Raman gain coefficient of the prepared glasses is ranging from 6.34x10⁻¹² to 5x10⁻¹⁰ m/W. All the prepared glasses have a higher Raman gain coefficient than that is reported for silica (1.85x 10⁻¹³mW⁻¹), see Table 2. Al₂O₃ modified glasses have the highest Raman gain coefficient. It can be noticed also that doping with Er₂O₃ increases the Raman gain coefficient for the prepared glasses with Al₂O₃ modified glass sample has the highest Raman gain coefficient. The Raman gain coefficient of the prepared glasses was compared also with other glass systems, see Table 2.

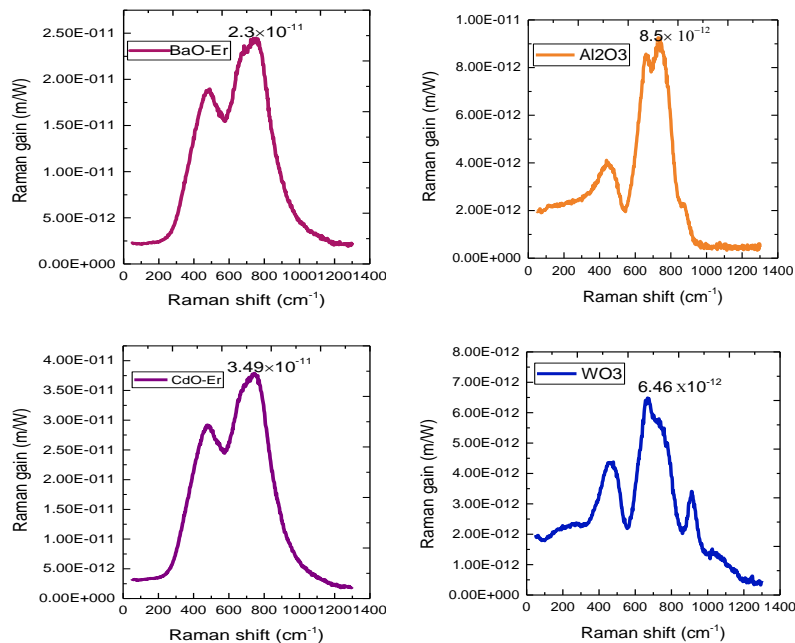


Fig. Raman gain coefficient of prepared glasses.

Table 2. The Raman gain coefficient of prepared glasses.

Sample Code	Composition	Gain m/W	Ref.
W	70TeO ₂ -5WO ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂	6.46 × 10 ⁻¹²	Present work
W-Er	70TeO ₂ -5WO ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	2.76 × 10 ⁻¹¹	Present work
Cd	70TeO ₂ -5CdO-10P ₂ O ₅ -10ZnO-5PbF ₂	6.34 × 10 ⁻¹²	Present work
Cd-Er	70TeO ₂ -5CdO-10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	3.49 × 10 ⁻¹¹	Present work
Al	70TeO ₂ -5Al ₂ O ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂	8.5 × 10 ⁻¹²	Present work
Al-Er	70TeO ₂ -5Al ₂ O ₃ -10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	5 × 10 ⁻¹⁰	Present work
Sr	70TeO ₂ -5SrO-10P ₂ O ₅ -10ZnO-5PbF ₂	6.65 × 10 ⁻¹²	Present work
Sr-Er	70TeO ₂ -5SrO-10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	1.23 × 10 ⁻¹¹	Present work
Ba	70TeO ₂ -5BaO-10P ₂ O ₅ -10ZnO-5PbF ₂	6.66 × 10 ⁻¹²	Present work
Ba-Er	70TeO ₂ -5BaO-10P ₂ O ₅ -10ZnO-5PbF ₂ + 600ppm Er ₂ O ₃	2.3 × 10 ⁻¹¹	Present work
	80TeO ₂ -10Na ₂ O-10ZnO 90TeO ₂ -5WO ₃ -5Nb ₂ O ₅ 70TeO ₂ -25WO ₃ -5Bi ₂ O ₃	19.9 × 10 ⁻¹³ 29.7 × 10 ⁻¹³ 23.9 × 10 ⁻¹³	[2]
	75TeO ₂ -5WO ₃ -15Nb ₂ O ₅ -5CuO 75TeO ₂ -5WO ₃ -15Nb ₂ O ₅ -5Na ₂ O	0.14 × 10 ⁻¹² 4.43 × 10 ⁻¹²	[35]
	77TeO ₂ -10Na ₂ O-10ZnO-3PbO 65TeO ₂ -10Na ₂ O-25ZnF ₂ 50TeO ₂ -50TiO 85TeO ₂ -15WO ₃	17 × 10 ⁻¹³ 7.5 × 10 ⁻¹³ 52 × 10 ⁻¹³ 38 × 10 ⁻¹³	[36]

4. Conclusions

The glass composition affects the Amplitude and the energy of the Boson peak. The transformation of Te₄ to Te₃ is more obvious in Al₂O₃ modified glass sample. Raman bands also shift to higher energy after doping while Boson peak shifts to lower frequency to satisfy the neutrality condition. As W-O bond is stronger than Te-O bond, Addition of WO₃ increases the connectivity of the glass network due to the formation of Te-O-W bridging bonds.

Al₂O₃ could cross-link strongly the glass network by Te-O-Al bridges. ZnO or/and divalent alkaline-earth ion (M²⁺) and oxygen anions affect the connection of Te-O-Te and lead to the termination of Te-O- with M²⁺ ions and finally, TeO₄ units are converted to a TeO₃ with a terminating double bond of Te=O. Doping with Er³⁺ ions results in the deformation of Te-O-Te linkages. Raman gain was calculated and found to increase after doping. Al₂O₃ modified glasses have the highest Raman gain

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